## Features

$\rightarrow$ Near-Zero propagation delay
$\rightarrow$ 5-ohm switches connect inputs to outputs
$\rightarrow$ High signal passing bandwidth ( 500 MHz )
$\rightarrow$ Beyond Rail-to-Rail switching

- 0 to 5 V switching with 3.3 V power supply
- 0 to 3.3 V switching with 2.5 V power supply
$\rightarrow \quad 5 \mathrm{~V}$ I/O tolerant with supply in OFF and ON state
$\rightarrow \quad 1.8 \mathrm{~V}, 2.5 \mathrm{~V}$ and 3.3 V supply voltage operation
$\rightarrow$ Hot Insertion Capable
$\rightarrow$ Industrial Operating Temperature: $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$\rightarrow \quad 8 \mathrm{kV}$ ESD Protection (human body model)
$\rightarrow$ Latch-up Performance: $>200 \mathrm{~mA}$ per JESD17
$\rightarrow \quad$ Packaging (Pb-free \& Green available):
-20-pin 150-mil wide plastic QSOP (Q)
-20-pin 173-mil wide plastic TSSOP (L)
-20-pin TQFN (ZH)


## Description

The PI3CH800 is a low voltage, 8-channel switch designed with fast individual enables. The switch introduces no additional ground bounce noise or additional propagation delay.
The PI3CH800 device has active low enables. It is very useful in switching signals that have high bandwidth ( 500 MHz ).

## Applications

$\rightarrow$ High Bandwidth Data Switching
$\rightarrow$ Hot-Docking
$\rightarrow$ Analog Signal Switching
$\rightarrow$ Differential Signal Switching

## Pin Configuration



## Pin Description

| Pin No | Pin Name | Description |
| :---: | :---: | :---: |
| 19 | $\overline{\mathrm{EN}}$ | Switch Enables |
| $2,3,4,5,6$, <br> $7,8,9$ | A0-A7 | A Ports |
| 10 | GND | Ground |
| $11,12,13$, <br> $14,15,16$, <br> 17,18 | B0-B7 | B Ports |
| 20 | $\mathrm{~V}_{\mathrm{CC}}$ | Power |

## Truth Table ${ }^{(1)}$

| $\overline{\mathbf{E N}}$ | $\mathbf{A x}$ | Function |
| :---: | :---: | :---: |
| H | $\mathrm{Hi}-\mathrm{Z}$ | Disconnect |
| L | Bx | Connect |

Note:

1. H=High Voltage Level; L=Low Voltage Level; Hi-Z=High Impedance

PI3CH800

## Maximum Ratings

Storage Temperature ..... $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Ambient Temperature with Power Applied.

$\qquad$
$40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$Supply Voltage to Ground Potential
$\qquad$ -0.5 V to +4.6 V-0.5 V to +4.6 V-0.5 V to +6.0 V
DC Output Current120 mA
Power Dissipation. ..... 0.5 W

## Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device This is a stress rating only and functional operation of the device at these or any other condi-tions above those indicated in the operational sec-tions of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## DC Electrical Characteristics

3.3V supply (Over operating range, $\mathrm{T}_{\mathrm{A}}=-40 \sim+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%$, unless otherwise noted)

| Symbol | Description | Test Conditions ${ }^{(1)}$ | Min | Typ ${ }^{(2)}$ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IH}}$ | Control Input HIGH Voltage | Guaranteed Logic HIGH Level | 2.0 | - | - | V |
| $\mathrm{V}_{\text {IL }}$ | Control Input LOW Voltage | Guaranteed Logic LOW Level | -0.5 | - | 0.8 | V |
| $\mathrm{V}_{\text {IK }}$ | Clamp Diode Voltage | $\mathrm{V}_{\mathrm{CC}}=$ Min., $\mathrm{I}_{\mathrm{IN}}=-18 \mathrm{~mA}$ | - | -1.3 | -1.8 | V |
| $\mathrm{I}_{\mathrm{IH}}$ | Input HIGH Current | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IL }}$ | Input Low Current | $\mathrm{V}_{\text {CC }}=$ Max., $\mathrm{V}_{\text {IN }}=\mathrm{GND}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {OZH }}$ | High-Impedance Current | $0 \leq \mathrm{A}, \mathrm{B} \leq \mathrm{V}_{\mathrm{CC}}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\text {ON }}$ | Switch On-Resistance ${ }^{(3)}$ | $\begin{aligned} & \hline \mathrm{V}_{\mathrm{CC}}=\mathrm{Min} ., \mathrm{V}_{\mathrm{IV}}=0.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{ON}}=-48 \mathrm{~mA} \text { or }-64 \mathrm{~mA} \\ & \hline \mathrm{~V}_{\mathrm{CC}}=\mathrm{Min} ., \mathrm{V}_{\mathrm{IN}}=3.6 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{ON}}=-15 \mathrm{~mA} \end{aligned}$ | - | 4 5 | 6 8 | $\Omega$ |

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ ambient and maximum loading.
3. Measured by the voltage drop between A and B pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two $(\mathrm{Ax}, \mathrm{Bx})$ pins.
2.5 V supply (Over operating range, $\mathrm{T}_{\mathrm{A}}=-40 \sim+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V} \pm 10 \%$, unless otherwise noted)

| Symbol | Description | Test Conditions ${ }^{(1)}$ | Min | Typ ${ }^{(2)}$ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IH}}$ | Control Input HIGH Voltage | Guaranteed Logic HIGH Level | 1.8 | - | $\mathrm{V}_{\mathrm{CC}}+0.3$ | V |
| $\mathrm{V}_{\text {IL }}$ | Control Input LOW Voltage | Guaranteed Logic LOW Level | -0.3 | - | 0.8 | V |
| $\mathrm{V}_{\text {IK }}$ | Clamp Diode Voltage | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{I}_{\text {IN }}=-6 \mathrm{~mA}$ | - | -0.7 | -1.8 | V |
| $\mathrm{I}_{\mathrm{IH}}$ | Input HIGH Current | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{IL}}$ | Input Low Current | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{V}_{\text {IN }}=$ GND | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {OZH }}$ | High-Impedance Current | $0 \leq \mathrm{A}, \mathrm{B} \leq \mathrm{V}_{\mathrm{CC}}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\text {ON }}$ | Switch On-Resistance ${ }^{(3)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=\mathrm{Min} ., \mathrm{V}_{\mathrm{IN}}=0.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{ON}}=-48 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CC}}=\mathrm{Min} ., \mathrm{V}_{\mathrm{IN}}=2.25 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{ON}}=-15 \mathrm{~mA} \end{aligned}$ | - | 4 7 | 8 14 | $\Omega$ |

## Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $\mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ ambient and maximum loading.
3. Measured by the voltage drop between A and B pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two $(\mathrm{Ax}, \mathrm{Bx})$ pins.

PI3CH800
1.8 V supply (Over operating range, $\mathrm{T}_{\mathrm{A}}=-40 \sim+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V} \pm 10 \%$, unless otherwise noted)

| Symbol | Description | Test Conditions ${ }^{(1)}$ | Min | Typ ${ }^{(2)}$ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IH}}$ | Control Input HIGH Voltage | Guaranteed Logic HIGH Level | 1.2 | - | $\mathrm{V}_{\mathrm{CC}}+0.3$ | V |
| $\mathrm{V}_{\text {IL }}$ | Control Input LOW Voltage | Guaranteed Logic LOW Level | -0.3 | - | 0.6 | V |
| $\mathrm{V}_{\mathrm{IK}}$ | Clamp Diode Voltage | $\mathrm{V}_{\mathrm{CC}}=$ Max., $\mathrm{I}_{\text {IN }}=-6 \mathrm{~mA}$ | - | -0.7 | -1.8 | V |
| $\mathrm{I}_{\mathrm{H}}$ | Input HIGH Current | $\mathrm{V}_{\text {CC }}=$ Max., $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {IL }}$ | Input Low Current | $\mathrm{V}_{\text {CC }}=$ Max., $\mathrm{V}_{\text {IN }}=\mathrm{GND}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {OZH }}$ | High-Impedance Current | $0 \leq \mathrm{A}, \mathrm{B} \leq \mathrm{V}_{\mathrm{CC}}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\mathrm{ON}}$ | Switch On-Resistance ${ }^{(3)}$ | $\begin{array}{\|l} \hline \mathrm{V}_{\mathrm{CC}}=\mathrm{Min} ., \mathrm{V}_{\mathrm{IN}}=0.0 \mathrm{~V} \\ \mathrm{I}_{\mathrm{ON}}=-48 \mathrm{~mA} \\ \hline \mathrm{~V}_{\mathrm{CC}}=\mathrm{Min} ., \mathrm{V}_{\mathrm{IN}}=2.25 \mathrm{~V} \\ \mathrm{I}_{\mathrm{ON}}=-15 \mathrm{~mA} \\ \hline \end{array}$ | - | 4 10 | 8 25 | $\Omega$ |

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $\mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ ambient and maximum loading.
3. Measured by the voltage drop between A and B pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two ( $\mathrm{Ax}, \mathrm{Bx}$ ) pins.

Capacitance ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz}$ )

| Symbol ${ }^{(1)}$ | Description | Test Conditions | Typ ${ }^{(2)}$ | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance | $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$ | 2.0 | pF |
| $\mathrm{C}_{\text {OFF }}$ | A/B Capacitance, Switch Off |  | 3.5 |  |
| $\mathrm{C}_{\text {ON }}$ | A/B Capacitance, Switch On |  | 7.0 |  |

Note:

1. These parameters are determined by device characterization but are not production tested

## Power Supply Characteristics

| Symbol | Description | Test Conditions ${ }^{(\mathbf{1 )}}$ | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Quiescent Power Supply Current | $\mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=$ GND or $\mathrm{V}_{\mathrm{CC}}$ | - | 0.2 | 0.5 | mA |

Note:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
2. Typical values are at $+25^{\circ} \mathrm{C}$ ambient

## Dynamic Electrical Characteristics

(Over Operating Range, $\mathrm{T}_{\mathrm{A}}=-40 \sim+85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Symbol | Description | Test Conditions | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{X}_{\text {TALK }}$ | Crosstalk | 10 MHz | - | -60 | - |  |
| $\mathrm{O}_{\text {IRR }}$ | Off-Isolation | 10 MHz | dB |  |  |  |
| BW | -3 dB Bandwidth | See test Diagram | - | -60 | - |  |

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## Switch Characteristics

Over 3.3V Operating Range

| Symbol | Description | $\text { Test Conditions }{ }^{(1)}$ | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PLH, }} \mathrm{t}_{\text {PHL }}$ | Propagation Delay ${ }^{(2,3)}$ Ax to Bx, Bx to Ax | See test Diagram | - | - | 0.3 | ns |
| $\mathrm{t}_{\text {PZH, }} \mathrm{t}_{\text {PZL }}$ | Enable Time $\overline{\mathrm{EN}}$ to Ax or Bx | See test Diagram | 1.5 | - | 9.0 |  |
| $\mathrm{t}_{\text {PHZ, }} \mathrm{t}_{\text {PLZ }}$ | Disable Time $\overline{\mathrm{EN}}$ to Ax or Bx | See test Diagram | 1.5 | - | 9.0 |  |

Note:

1. See test circuit and waveforms.
2. This parameter is guaranteed but not tested on Propagation Delays.
3. The switch contributes no propagation delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.30 ns for 10 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Over 2.5V Operating Range

| Symbol | Description | Test Conditions ${ }^{(1)}$ | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PLH, }} \mathrm{t}_{\text {PHL }}$ | Propagation Delay ${ }^{(2,3)}$ Ax to Bx, Bx to Ax | See test Diagram | - | - | 0.3 | ns |
| $\mathrm{t}_{\text {PZH, }} \mathrm{t}_{\text {PZL }}$ | Enable Time $\overline{\mathrm{EN}}$ to Ax or Bx | See test Diagram | 1.5 | - | 15.0 |  |
| $\mathrm{t}_{\text {PHZ, }} \mathrm{t}_{\text {PLZ }}$ | Disable Time EN to Ax or Bx | See test Diagram | 1.5 | - | 12.0 |  |

Note:

1. See test circuit and waveforms.
2. This parameter is guaranteed but not tested on Propagation Delays.
3. The switch contributes no propagation delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.30 ns for 10 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Over 1.8V Operating Range

| Symbol | Description | Test Conditions ${ }^{(\mathbf{1 )}}$ | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| t $_{\text {PLH, }} \mathrm{t}_{\text {PHL }}$ | Propagation Delay ${ }^{(2,3)}$ Ax to Bx, Bx to Ax | See test Diagram | - | - | 0.3 |  |
| t $_{\text {PZH, }} \mathrm{t}_{\text {PZL }}$ | Enable Time EN to Ax or Bx | See test Diagram | 1.5 | - | 25.0 | ns |
| t $_{\text {PHZ, }, \mathrm{t}_{\text {PLZ }}}$ | Disable Time EN to Ax or Bx | See test Diagram | 1.5 | - | 12.0 |  |

Note:

1. See test circuit and waveforms.
2. This parameter is guaranteed but not tested on Propagation Delays.
3. The switch contributes no propagation delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.30 ns for 10 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

## Test Circuit for Electrical Characteristics



Notes:

1. $\mathrm{C}_{\mathrm{L}}=$ Load capacitance: includes jig and probe capacitance.
2. $\mathrm{R}_{\mathrm{T}}=$ Termination resistance: should be equal to Zout of the Pulse Generator
3. All input impulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50-\mathrm{ohm}, \mathrm{t}_{\mathrm{R}} \leq 2.5 \mathrm{~ns}, \mathrm{t}_{\mathrm{F}} \leq 2.5 \mathrm{~ns}$.
4. The outputs are measured one at a time with one transition per measurement.

## Switch Positions

| Te | Switch |
| :---: | :---: |
| t $_{\text {PLZ }}, \mathrm{t}_{\text {PZL }}$ | 6.0 V |
| ${\text { tPHZ, } \mathrm{t}_{\text {PZH }}}^{\text {Grop Delay }}$ | GND |
| Open |  |

## Test Circuit for Dynamic Electrical Characteristics



## Switching Waveforms



## Applications Information

## Logic Inputs

The logic control inputs can be driven up to 3.6 V regardless of the supply voltage. For example, given a +3.3 V supply, $\overline{\mathrm{EN}}$ may be driven LOW to 0 V and HIGH to 3.6 V . Driving $\overline{\mathrm{EN}}$ Rail-to-Rail minimizes power consumption.

## Hot Insertion

For Datacom and Telecom applications that have ten or more volts passing through the backplane, a high voltage from the power supply may be seen at the device input pins during hot insertion. The PI3CH400 devices have maximum limits of 6 V and 120 mA for 20 ns . If the power is higher or applied for a longer time or repeatedly reaches the maximum limits, the devices can be damaged.

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

## Part Marking



Z: Fixed Code
YY: Year
WW: Workweek
First G: Assembly Site Code
Last G: Wafer Fab Site Code


Z: Fixed Code
Y: Year
W: Workweek
First G: Assembly Site Code Last G: Wafer Fab Site Code

Q Package


Z: Fixed Code
YY: Year
WW: Workweek
1st X: Assembly Site Code
2nd X: Fab Site Code

## Packaging Mechanical

20-TSSOP(L)


PI3CH800

## 20-TQFN(ZH)



20 Ref.


Notes:

1. All dimensions are in mm . Angles in degrees
2. Coplanarity applies to the exposed pad as well as the terminals
3. Refer JEDEC MO-241
4. Recommended land pattern is for reference only
5. Thermal pad soldering area (mesh stencile design is recommended)

| 4 Perabling Serial connectivity | DATE: 09/07/10 |
| :--- | :--- |
| DESCRIPTION: 20-contact, Very Thin Quad Flat No-Lead (TQFN) |  |
| PACKAGE CODE: ZH20 |  |
| DOCUMENT CONTROL \#: PD-2032 | REVISION: B |

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## Ordering Information

| Part Number | Package Cede | Package Description |
| :--- | :---: | :--- |
| PI3CH800LEX | L | 20-Pin, 173mil-Wide (TSSOP) |
| PI3CH800ZHEX | ZH | 20-Pin, Very Thin Quad Flat No-Lead (TQFN) |
| PI3CH800QEX | Q | 20-Pin, 150mil-Wide (QSOP) |

## Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) \& 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
4. $\mathrm{E}=\mathrm{Pb}$-free and Green
5. $\quad \mathrm{X}$ suffix $=$ Tape/Reel

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PI3C3305UEX PI3B3861QE PI3B3245QEX PI3B3245QE PI3CH800ZHEX PI3CH1000LE PI3CH400ZBEX PI3CH401LE PI3CH401LEX TC7WBL3305CFK(5L,F 74CB3Q3125DBQRE4 TC7WBL3305CFK,LF SN74CBT16245CDGGR 72V90823PQFG PI3B3861QEX PI3C3245QE PI5C3384QE PI3CH281QE PI3C3306LE PI3C3305LE PI5C3245LE PI3CH400LE PI3B3245LEX PI3B3245LE PI3C3306LEX PI5C3245LEX PI3B3126LE PI3B3126LEX 74CBTLV3862PGG QS3VH126QG QS3VH16861PAG QS3VH126S1G QS3L384QG

